**BU4525DX** 

### **GENERAL DESCRIPTION**

Enhanced performance, new generation, high-voltage, high-speed switching npn transistor in a plastic full-pack envelope with an integrated damper diode intended for use in horizontal deflection circuits of colour television receivers and p.c monitors. Features exceptional tolerance to base drive and collector current load variations resulting in a very low worst case dissipation.

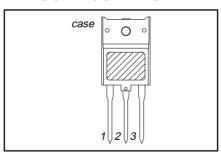
### **QUICK REFERENCE DATA**

| SYMBOL                                 | PARAMETER                             | CONDITIONS  | TYP.  | MAX.  | UNIT |
|--|---------------------------------------|---|-------|-------|------|
| V <sub>CESM</sub>                      | Collector-emitter voltage peak value  | $V_{BF} = 0 \text{ V}$                                  | -     | 1500  | V    |
| V <sub>CEO</sub>                       | Collector-emitter voltage (open base) |   | -     | 800   | V    |
| I <sub>C</sub>                         | Collector current (DC)                |   | -     | 12    | Α    |
| 1 1                                    | Collector current peak value          |   | -     | 30    | Α    |
| P <sub>tot</sub><br>V <sub>CEsat</sub> | Total power dissipation               | T <sub>hs</sub> ≤ 25 °C                                 | -     | 45    | W    |
| V <sub>CEsat</sub>                     | Collector-emitter saturation voltage  | $I_{\rm C} = 9.0 \text{ A}; I_{\rm B} = 2.25 \text{ A}$ | -     | 3.0   | V    |
| Csat                                   | Collector saturation current          | f = 16 kHz  | 9.0   | -     | Α    |
| Coat                                   |                                       | f = 70 kHz  | t.b.f | -     | Α    |
| $V_{F}$                                | Diode forward voltage                 | $I_{\rm F} = 9.0  \text{A}$                             | -     | 2.2   | V    |
| t <sub>f</sub>                         | Fall time                             | I <sub>Csat</sub> = 9.0 A;f = 16 kHz<br>f = 70 kHz      | 0.4   | 0.55  | μs   |
|  |                                       | f = 70 kHz  | t.b.f | t.b.f | μs   |

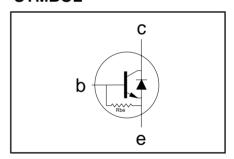
### **PINNING - SOT399**

| PIN  | DESCRIPTION |  |
|------|-------------|--|
| 1    | base        |  |
| 2    | collector   |  |
| 3    | emitter     |  |
| case | isolated    |  |

### **PIN CONFIGURATION**



### **SYMBOL**



## **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

| SYMBOL             | PARAMETER                             | CONDITIONS              | MIN. | MAX. | UNIT |
|--------------------|---------------------------------------|-------------------------|------|------|------|
| $V_{CESM}$         | Collector-emitter voltage peak value  | $V_{BE} = 0 \text{ V}$  | -    | 1500 | V    |
| $V_{CEO}$          | Collector-emitter voltage (open base) |                         | -    | 800  | V    |
| I <sub>C</sub>     | Collector current (DC)                |                         | -    | 12   | Α    |
| I <sub>CM</sub>    | Collector current peak value          |                         | -    | 30   | Α    |
| I I <sub>B</sub>   | Base current (DC)                     |                         | -    | 8    | Α    |
| I <sub>BM</sub>    | Base current peak value               |                         | -    | 12   | Α    |
| -I <sub>BM</sub>   | Reverse base current peak value 1     |                         | -    | 7    | Α    |
| P <sub>tot</sub>   | Total power dissipation               | T <sub>hs</sub> ≤ 25 °C | -    | 45   | W    |
| T <sub>stq</sub>   | Storage temperature                   | 110                     | -55  | 150  | °C   |
| T <sub>j</sub> sig | Junction temperature                  |                         | -    | 150  | °C   |

<sup>1</sup> Turn-off current.

BU4525DX

## THERMAL RESISTANCES

| SYMBOL               | PARAMETER            | CONDITIONS             | TYP. | MAX. | UNIT |
|----------------------|----------------------|------------------------|------|------|------|
| R <sub>th j-hs</sub> | Junction to heatsink | with heatsink compound | -    | 2.8  | K/W  |
| R <sub>th j-a</sub>  | Junction to ambient  | in free air            | 35   | -    | K/W  |

## **ISOLATION LIMITING VALUE & CHARACTERISTIC**

T<sub>hs</sub> = 25 °C unless otherwise specified

| SYMBOL            | PARAMETER   | CONDITIONS                       | MIN. | TYP. | MAX. | UNIT |
|-------------------|---|----------------------------------|------|------|------|------|
| V <sub>isol</sub> | Repetitive peak voltage from all three terminals to external heatsink | R.H. ≤ 65 % ; clean and dustfree | 1    | -    | 2500 | V    |
| C <sub>isol</sub> | Capacitance from T2 to external heatsink                              | f = 1 MHz                        | -    | 22   | -    | pF   |

# STATIC CHARACTERISTICS

 $T_{hs}$  = 25 °C unless otherwise specified

| SYMBOL                               | PARAMETER                              | CONDITIONS  | MIN. | TYP.  | MAX. | UNIT     |
|--------------------------------------|--|---|------|-------|------|----------|
| I <sub>CES</sub>                     | Collector cut-off current <sup>2</sup> | $V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax}, V_{BE} = 0 \text{ V}; V_{CE} = V_{CESMmax};$ | -    | -     | 1.0  | mA       |
| I <sub>CES</sub>                     |  | $V_{BE} = 0 V; V_{CE} = V_{CESMmax};$   | -    | -     | 2.0  | mA       |
| D\/                                  | Emitter-base breakdown voltage         | $T_{j} = 125 ^{\circ}\text{C}$<br>$I_{B} = 600 \text{mA}$                                 | 7.5  | 13.5  |      |          |
| BV <sub>EBO</sub><br>R <sub>be</sub> | Base-emitter resistance                | $V_{\rm FR} = 7.5 \text{ V}$  | 7.5  | 50    |      | $\Omega$ |
| V <sub>CEOsust</sub>                 | Collector-emitter sustaining voltage   | $I_B = 0 \text{ A}; I_C = 100 \text{ mA};$  | 800  | -     | -    | V        |
|                                      |  | L = 25  mH  |      |       |      |          |
| V <sub>CEsat</sub>                   | Collector-emitter saturation voltage   | $I_{\rm C} = 9.0 \text{ A}; I_{\rm B} = 2.25 \text{A}$                                    | -    | -     | 3.0  | V        |
| $V_{BEsat}$                          | Base-emitter saturation voltage        | $I_{\rm C} = 9.0 \text{ A}; I_{\rm B} = 2.25 \text{A}$                                    | 0.96 | 1.01  | 1.06 | V        |
| h <sub>FE</sub>                      | DC current gain                        | $I_{\rm C} = 1.0  \text{A};  V_{\rm CE} = 5  \text{V}$                                    | -    | t.b.f | -    |          |
| h <sub>FE</sub>                      | _                                      | $I_{\rm C} = 9.0 \text{ A}; V_{\rm CE} = 5 \text{ V}$                                     | 4.2  | 5.8   | 7.6  |          |
| V <sub>F</sub>                       | Diode forward voltage                  | $I_F = 9 A$   | -    | -     | 2.2  | V        |

## **DYNAMIC CHARACTERISTICS**

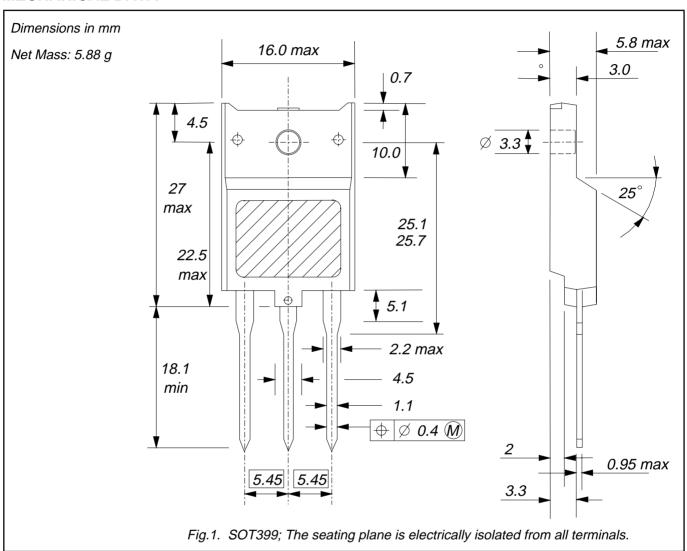
 $T_{hs} = 25$  °C unless otherwise specified

| SYMBOL                           | PARAMETER  | CONDITIONS  | TYP.           | MAX.           | UNIT     |
|----------------------------------|--|---|----------------|----------------|----------|
| C <sub>c</sub>                   | Collector capacitance                            | $I_E = 0 \text{ A}; V_{CB} = 10 \text{ V}; f = 1 \text{ MHz}$                     | 145            | ı              | pF       |
|                                  | Switching times (16 kHz line deflection circuit) | $I_{Csat} = 9.0 \text{ A}; I_{B1} = 1.8 \text{ A}$<br>$(I_{B2} = -4.5 \text{ A})$ |                |                |          |
| t <sub>s</sub><br>t <sub>f</sub> | Turn-off storage time<br>Turn-off fall time      |   | 3.7<br>0.4     | 4.5<br>0.55    | μs<br>μs |
|                                  | Switching times (70 kHz line deflection circuit) | $I_{Csat} = t.b.f$  |                |                |          |
| t <sub>s</sub>                   | Turn-off storage time Turn-off fall time         |   | t.b.f<br>t.b.f | t,b,f<br>t.b.f | μs<br>μs |

<sup>2</sup> Measured with half sine-wave voltage (curve tracer).

BU4525DX

## **MECHANICAL DATA**



### **Notes**

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

BU4525DX

#### **DEFINITIONS**

| Data sheet status         |   |  |  |  |
|---------------------------|---|--|--|--|
| Objective specification   | This data sheet contains target or goal specifications for product development.       |  |  |  |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |  |  |  |
| Product specification     | This data sheet contains final product specifications.                                |  |  |  |
| Limiting values           |   |  |  |  |

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### © Philips Electronics N.V. 1998

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.